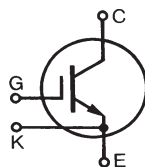


## GenX3™ A3-Class IGBTs

## IXGK120N60A3 IXGX120N60A3

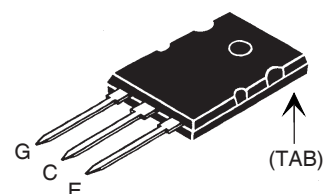
Ultra-Low  $V_{sat}$  PT IGBTs for  
up to 5kHz Switching



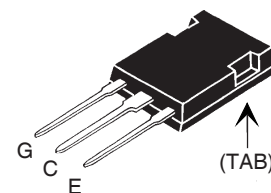
$$\begin{aligned} V_{CES} &= 600V \\ I_{C110} &= 120A \\ V_{CE(sat)} &\leq 1.35V \end{aligned}$$

| Symbol                        | Test Conditions                                                                                    | Maximum Ratings                |                  |
|-------------------------------|----------------------------------------------------------------------------------------------------|--------------------------------|------------------|
| $V_{CES}$                     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                                                    | 600                            | V                |
| $V_{CGR}$                     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GE} = 1\text{M}\Omega$                       | 600                            | V                |
| $V_{GES}$                     | Continuous                                                                                         | $\pm 20$                       | V                |
| $V_{GEM}$                     | Transient                                                                                          | $\pm 30$                       | V                |
| $I_{C25}$                     | $T_C = 25^\circ\text{C}$                                                                           | 200                            | A                |
| $I_{C110}$                    | $T_C = 110^\circ\text{C}$                                                                          | 120                            | A                |
| $I_{LRMS}$                    | Terminal Current Limit                                                                             | 75                             | A                |
| $I_{CM}$                      | $T_C = 25^\circ\text{C}$ , 1ms                                                                     | 600                            | A                |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15\text{V}$ , $T_{VJ} = 125^\circ\text{C}$ , $R_G = 1.5\Omega$<br>Clamped Inductive Load | $I_{CM} = 200$<br>@ $\leq 600$ | A<br>V           |
| $P_c$                         | $T_C = 25^\circ\text{C}$                                                                           | 780                            | W                |
| $T_J$                         |                                                                                                    | -55 ... +150                   | $^\circ\text{C}$ |
| $T_{JM}$                      |                                                                                                    | 150                            | $^\circ\text{C}$ |
| $T_{stg}$                     |                                                                                                    | -55 ... +150                   | $^\circ\text{C}$ |
| $T_L$                         | Maximum Lead Temperature for Soldering                                                             | 300                            | $^\circ\text{C}$ |
| $T_{SOLD}$                    | 1.6 mm (0.062 in.) from Case for 10                                                                | 260                            | $^\circ\text{C}$ |
| $M_d$                         | Mounting Torque ( IXGK )                                                                           | 1.13/10                        | Nm/lb.in.        |
| $F_c$                         | Mounting Force ( IXGX )                                                                            | 20..120/4.5..27                | N/lb.            |
| <b>Weight</b>                 | TO-264                                                                                             | 10                             | g                |
|                               | PLUS247                                                                                            | 6                              | g                |

TO-264 (IXGK)



PLUS 247™ (IXGX)



G = Gate                      E = Emitter  
C = Collector                TAB = Collector

### Features

- Optimized for Low Conduction Losses
- Square RBSOA
- High Current Handling Capability
- International Standard Packages

### Advantages

- High Power Density
- Low Gate Drive Requirement

### Applications

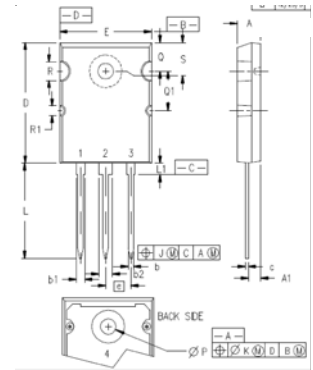
- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts
- Inrush Current Protection Circuits

| Symbol        | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified) | Characteristic Values |      |                             |
|---------------|-----------------------------------------------------------------------------|-----------------------|------|-----------------------------|
|               |                                                                             | Min.                  | Typ. | Max.                        |
| $V_{GE(th)}$  | $I_C = 500\mu\text{A}$ , $V_{CE} = V_{GE}$                                  | 3.0                   |      | 5.0 V                       |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0\text{V}$<br>$T_J = 125^\circ\text{C}$      |                       |      | 50 $\mu\text{A}$<br>1.25 mA |
| $I_{GES}$     | $V_{CE} = 0\text{V}$ , $V_{GE} = \pm 20\text{V}$                            |                       |      | $\pm 400$ nA                |
| $V_{CE(sat)}$ | $I_C = 100\text{A}$ , $V_{GE} = 15\text{V}$ , Note 1                        | 1.20                  | 1.35 | V                           |

| Symbol       | Test Conditions                                                                                                                 | Characteristic Values |      |                   |
|--------------|---------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|-------------------|
|              |                                                                                                                                 | Min.                  | Typ. | Max.              |
| $g_{fs}$     | $I_C = 60A, V_{CE} = 10V, \text{Note 1}$                                                                                        | 65                    | 108  | S                 |
| $C_{ies}$    | $V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$                                                                                           |                       | 14.8 | nF                |
| $C_{oes}$    |                                                                                                                                 |                       | 800  | pF                |
| $C_{res}$    |                                                                                                                                 |                       | 140  | pF                |
| $Q_{g(on)}$  | $I_C = I_{C110}, V_{GE} = 15V, V_{CE} = 0.5 \cdot V_{CES}$                                                                      |                       | 450  | nC                |
| $Q_{ge}$     |                                                                                                                                 |                       | 67   | nC                |
| $Q_{gc}$     |                                                                                                                                 |                       | 130  | nC                |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ C</math></b><br><br>$I_C = 100A, V_{GE} = 15V$<br><br>$V_{CE} = 480V, R_G = 1.5\Omega$  |                       | 39   | ns                |
| $t_{ri}$     |                                                                                                                                 |                       | 82   | ns                |
| $E_{on}$     |                                                                                                                                 |                       | 2.7  | mJ                |
| $t_{d(off)}$ |                                                                                                                                 |                       | 295  | ns                |
| $t_{fi}$     |                                                                                                                                 |                       | 260  | ns                |
| $E_{off}$    |                                                                                                                                 |                       | 6.6  | mJ                |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 125^\circ C</math></b><br><br>$I_C = 100A, V_{GE} = 15V$<br><br>$V_{CE} = 480V, R_G = 1.5\Omega$ |                       | 40   | ns                |
| $t_{ri}$     |                                                                                                                                 |                       | 83   | ns                |
| $E_{on}$     |                                                                                                                                 |                       | 3.5  | mJ                |
| $t_{d(off)}$ |                                                                                                                                 |                       | 420  | ns                |
| $t_{fi}$     |                                                                                                                                 |                       | 410  | ns                |
| $E_{off}$    |                                                                                                                                 |                       | 10.4 | mJ                |
| $R_{thJC}$   |                                                                                                                                 |                       |      | 0.16 $^\circ C/W$ |
| $R_{thCK}$   |                                                                                                                                 |                       | 0.15 | $^\circ C/W$      |

Note: 1. Pulse Test,  $t \leq 300\mu s$ ; Duty Cycle,  $d \leq 2\%$ .

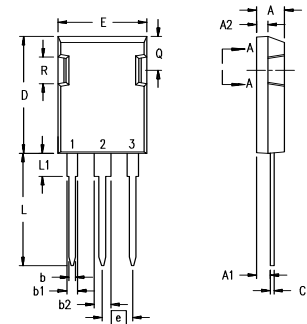
### TO-264 (IXGK) Outline



1 - GATE  
2, 4 - DRAIN (COLLECTOR)  
3 - SOURCE (EMITTER)

| SYM | INCHES   |       | MILLIMETERS |       |
|-----|----------|-------|-------------|-------|
|     | MIN      | MAX   | MIN         | MAX   |
| A   | .185     | .209  | 4.70        | 5.31  |
| A1  | .102     | .118  | 2.59        | 3.00  |
| b   | .037     | .055  | 0.94        | 1.40  |
| b1  | .087     | .102  | 2.21        | 2.59  |
| b2  | .110     | .126  | 2.79        | 3.20  |
| c   | .017     | .029  | 0.43        | 0.74  |
| D   | 1.007    | 1.047 | 25.58       | 26.59 |
| E   | .760     | .799  | 19.30       | 20.29 |
| e   | .215 BSC |       | 5.46 BSC    |       |
| J   | .000     | .010  | 0.00        | 0.25  |
| K   | .000     | .010  | 0.00        | 0.25  |
| L   | .779     | .842  | 19.79       | 21.39 |
| L1  | .087     | .102  | 2.21        | 2.59  |
| ØP  | .122     | .138  | 3.10        | 3.51  |
| Q   | .240     | .256  | 6.10        | 6.50  |
| Q1  | .330     | .346  | 8.38        | 8.79  |
| ØR  | .155     | .187  | 3.94        | 4.75  |
| ØR1 | .085     | .093  | 2.16        | 2.36  |
| S   | .243     | .253  | 6.17        | 6.43  |

### PLUS 247™ (IXGX) Outline



Terminals: 1 - Gate  
2 - Drain (Collector)  
3 - Source (Emitter)

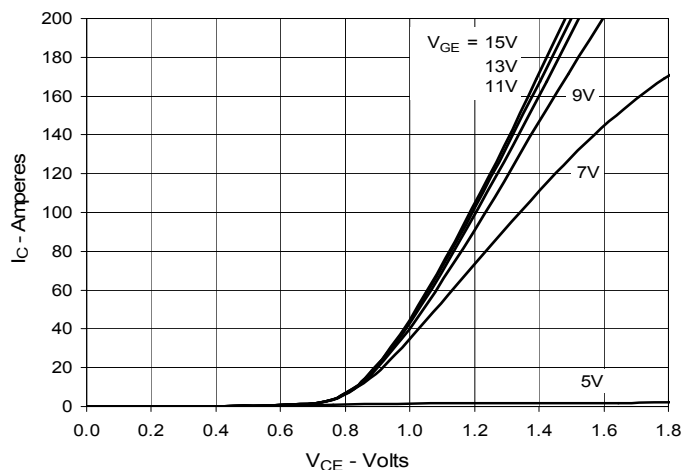
| Dim.           | Millimeter |       | Inches   |       |
|----------------|------------|-------|----------|-------|
|                | Min.       | Max.  | Min.     | Max.  |
| A              | 4.83       | 5.21  | .190     | .205  |
| A <sub>1</sub> | 2.29       | 2.54  | .090     | .100  |
| A <sub>2</sub> | 1.91       | 2.16  | .075     | .085  |
| b              | 1.14       | 1.40  | .045     | .055  |
| b <sub>1</sub> | 1.91       | 2.13  | .075     | .084  |
| b <sub>2</sub> | 2.92       | 3.12  | .115     | .123  |
| C              | 0.61       | 0.80  | .024     | .031  |
| D              | 20.80      | 21.34 | .819     | .840  |
| E              | 15.75      | 16.13 | .620     | .635  |
| e              | 5.45 BSC   |       | .215 BSC |       |
| L              | 19.81      | 20.32 | .780     | .800  |
| L1             | 3.81       | 4.32  | .150     | .170  |
| Q              | 5.59       | 6.20  | .220     | 0.244 |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

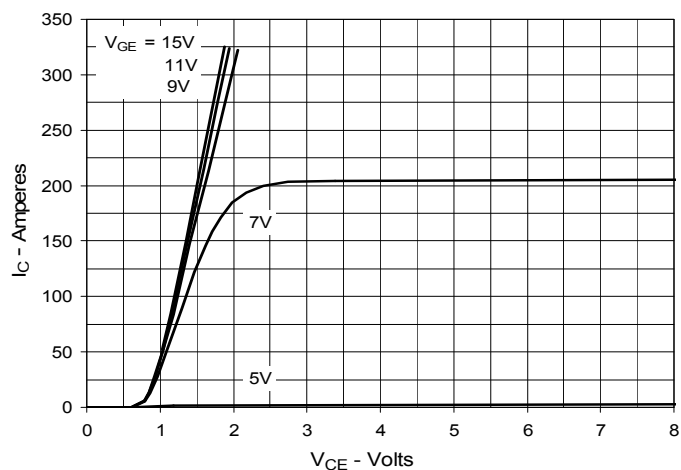
IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |              |              |              |              |              |             |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
| 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

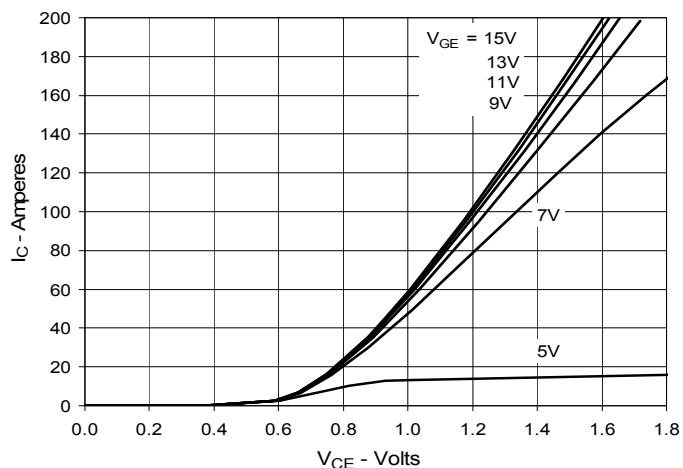
**Fig. 1. Output Characteristics**  
**@ 25°C**



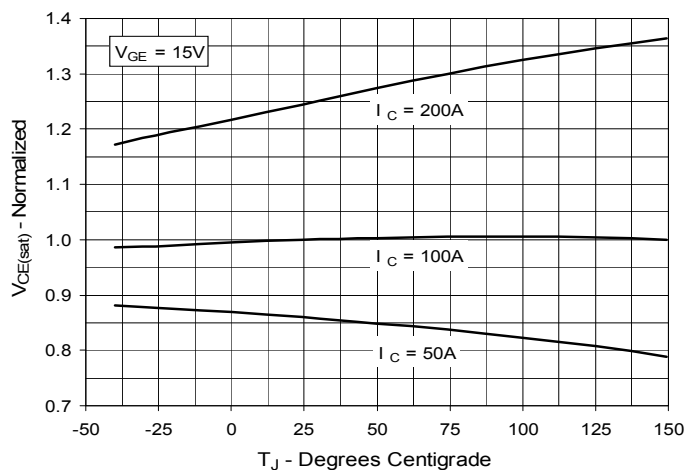
**Fig. 2. Extended Output Characteristics**  
**@ 25°C**



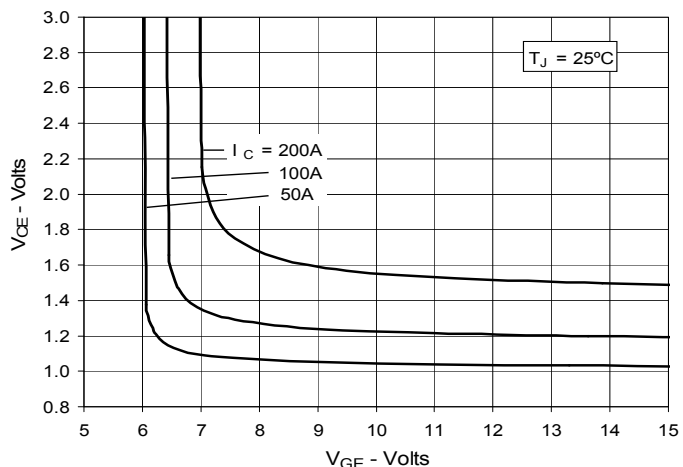
**Fig. 3. Output Characteristics**  
**@ 125°C**



**Fig. 4. Dependence of  $V_{CE(sat)}$  on**  
**Junction Temperature**



**Fig. 5. Collector-to-Emitter Voltage**  
**vs. Gate-to-Emitter Voltage**



**Fig. 6. Input Admittance**

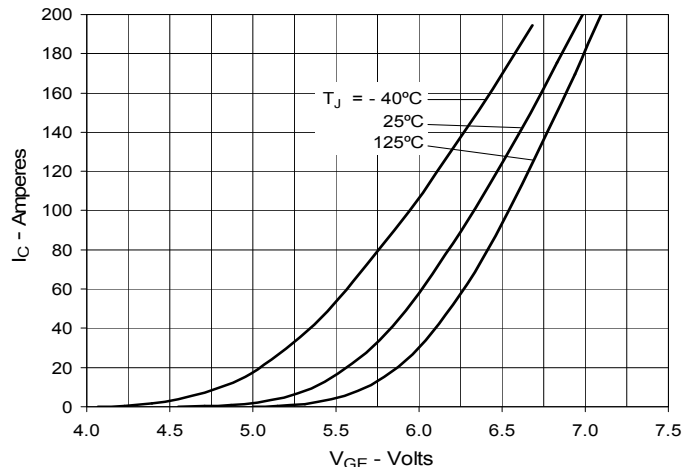


Fig. 7. Transconductance

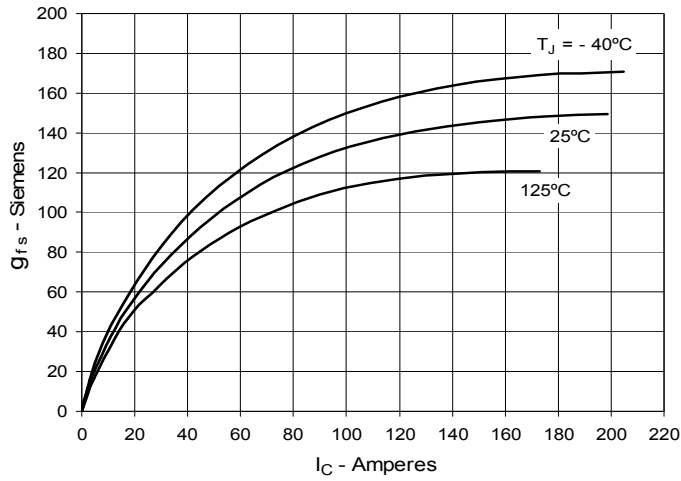


Fig. 8. Gate Charge

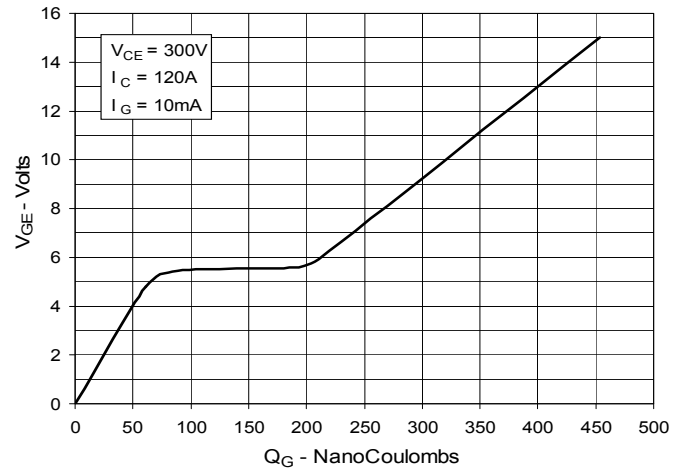


Fig. 9. Capacitance

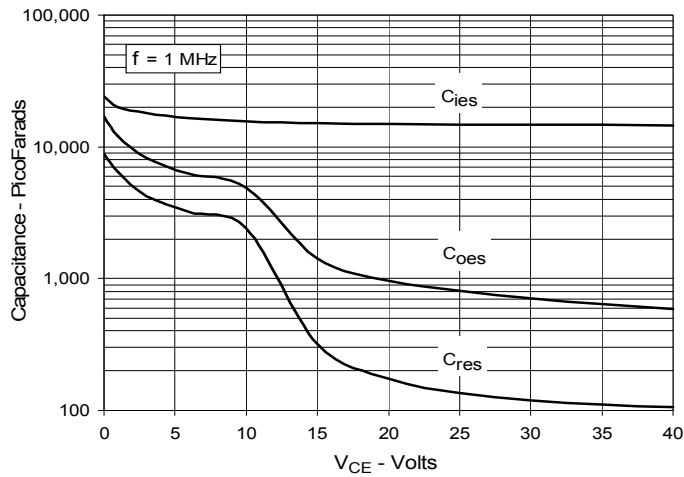


Fig. 10. Reverse-Bias Safe Operating Area

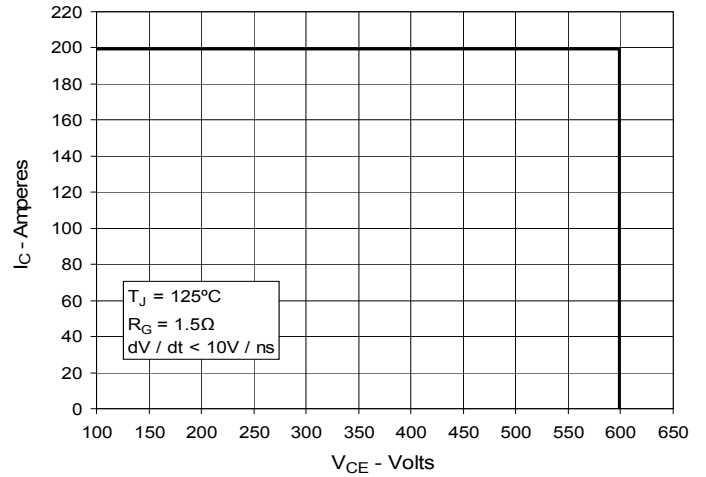
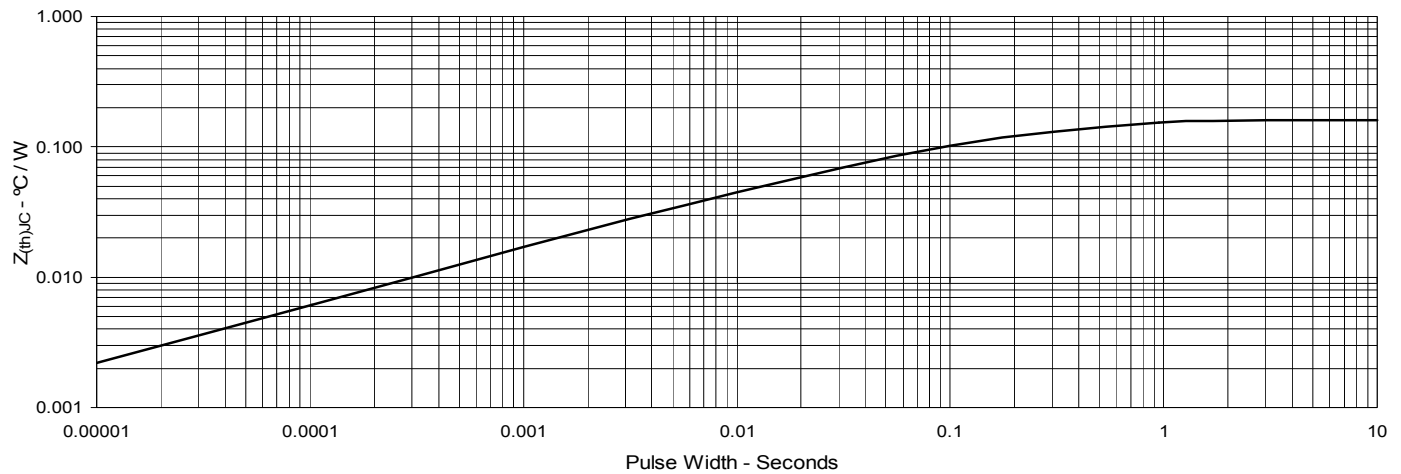
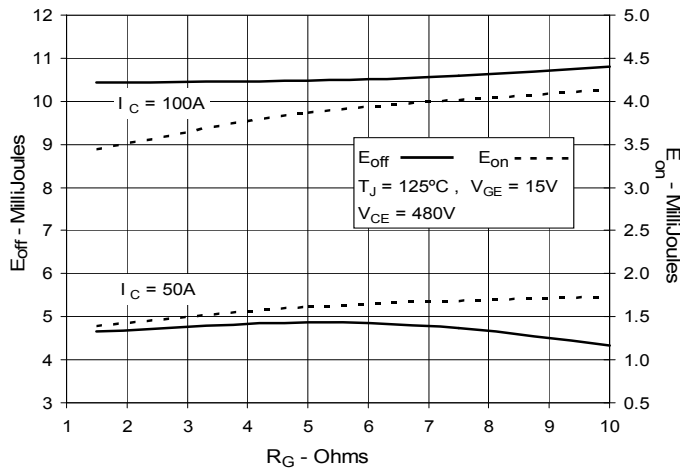


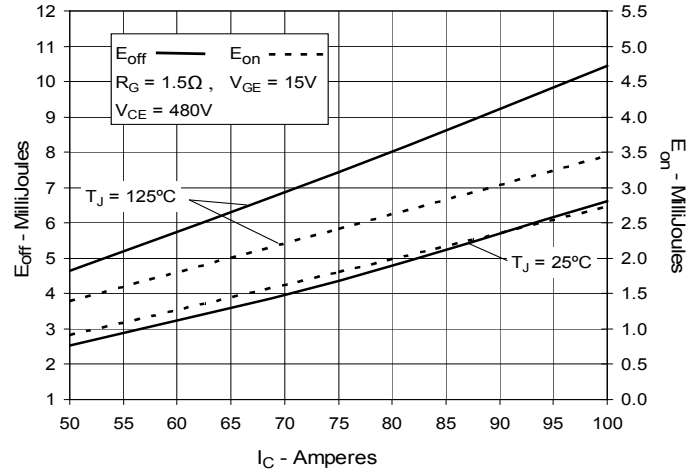
Fig. 11. Maximum Transient Thermal Impedance



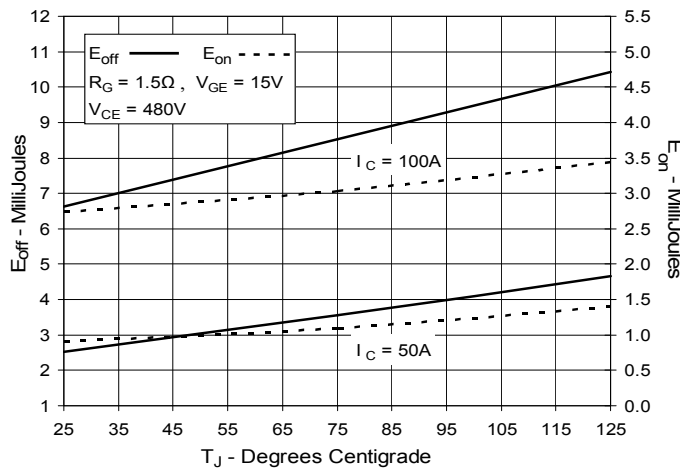
**Fig. 12. Inductive Switching  
Energy Loss vs. Gate Resistance**



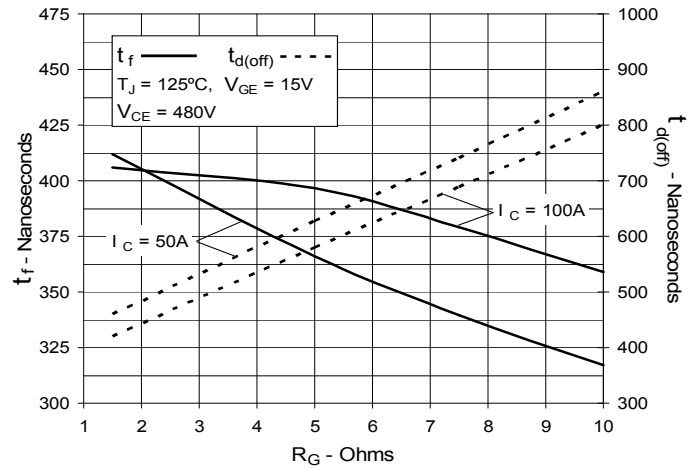
**Fig. 13. Inductive Switching  
Energy Loss vs. Collector Current**



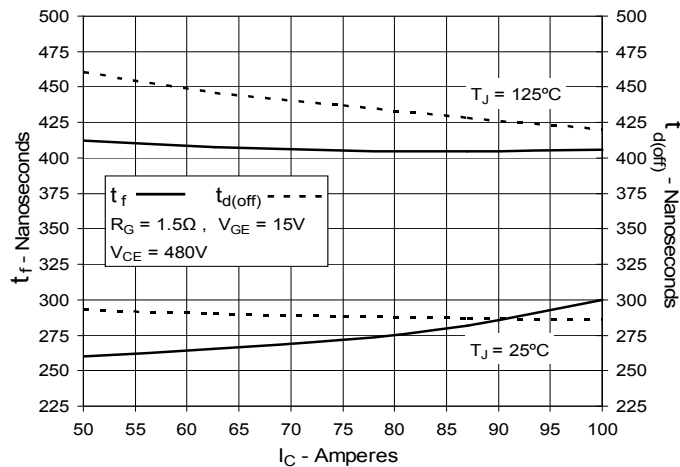
**Fig. 14. Inductive Switching  
Energy Loss vs. Junction Temperature**



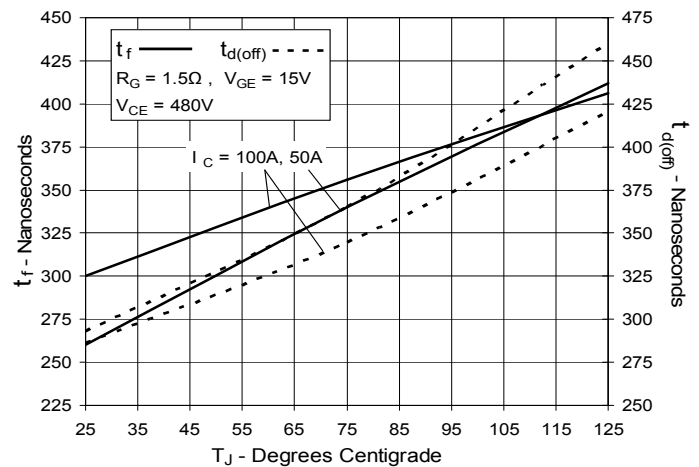
**Fig. 15. Inductive Turn-off  
Switching Times vs. Gate Resistance**



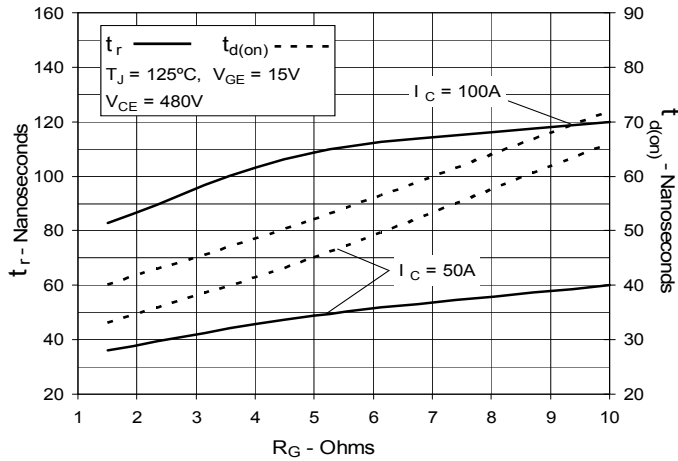
**Fig. 16. Inductive Turn-off  
Switching Times vs. Collector Current**



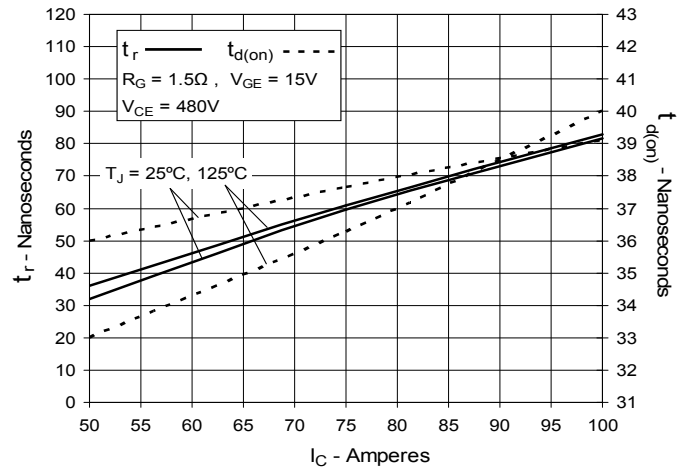
**Fig. 17. Inductive Turn-off  
Switching Times vs. Junction Temperature**



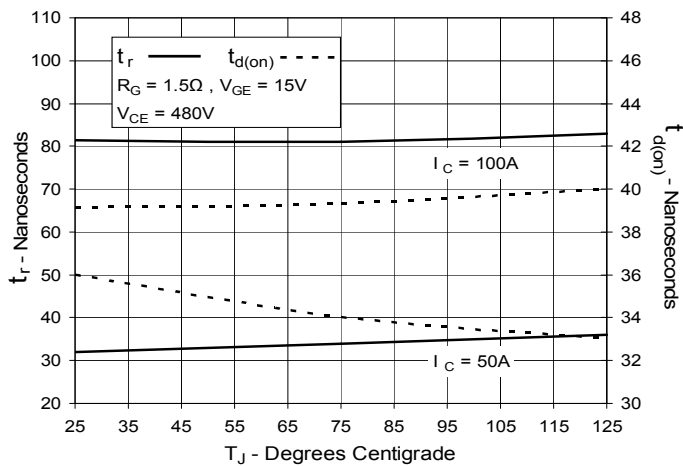
**Fig. 18. Inductive Turn-on  
Switching Times vs. Gate Resistance**



**Fig. 19. Inductive Turn-on  
Switching Times vs. Collector Current**



**Fig. 20. Inductive Turn-on  
Switching Times vs. Junction Temperature**





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